RENESAS BCR30AM-12LA

Triac

Medium Power Use

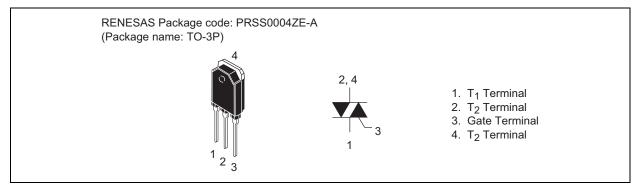
REJ03G0342-0300 Rev.3.00 Nov 30, 2007

Features

- I_{T(RMS)} : 30 A
- V_{DRM} : 600 V
- I_{FGT I}, I_{RGT I}, I_{RGT III} : 50 mA

Non-Insulated TypePlanar Passivation Type

Outline



Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Faiameter	Symbol	12		
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	600	V	
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V	

BCR30AM-12LA

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T(RMS)}	30	A	Commercial frequency, sine full wave, Tc = 75°C
Surge on-state current	I _{TSM}	300	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusing	l ² t	378	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G(AV)}	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	I _{GM}	2	А	
Junction temperature	Tj	- 40 to +125	°C	
Storage temperature	Tstg	- 40 to +125	°C	
Mass		4.8	g	Typical value

Notes: 1. Gate open.

Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}	_		3.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V _{TM}	_		1.6	V	Tc = 25°C, I _{TM} = 45A
Gate trigger voltage ^{Note2}	Ι	V _{FGTI}	_		2.5	V	$Tj = 25^{\circ}C, V_{D} = 6 V, R_{L} = 6 \Omega,$
	II	V _{RGTI}	_		2.5	V	R _G = 330 Ω
	III	V _{RGTIII}	—	_	2.5	V	7
Gate trigger currentNote2	Ι	I _{FGTI}	—	_	50	mA	$Tj = 25^{\circ}C, V_{D} = 6 V, R_{L} = 6 \Omega,$
	II	I _{RGTI}	—	_	50	mA	R _G = 330 Ω
	III	I _{RGTIII}	_	_	50	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th(j-c)}	_	_	1.2	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-stat commutating voltage ^{Note4}	te	(dv/dt)c	20	—	—	V/µs	Tj = 125°C

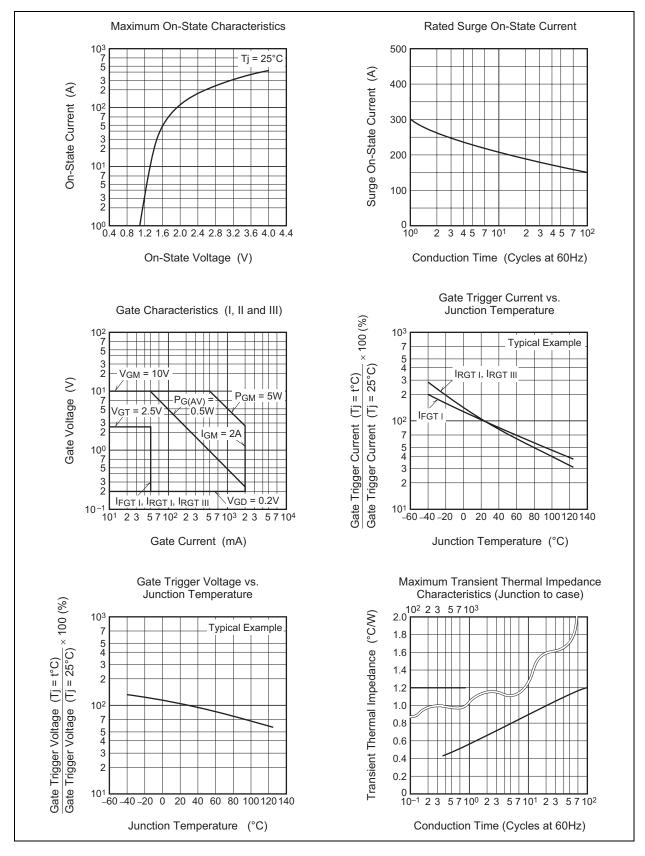
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

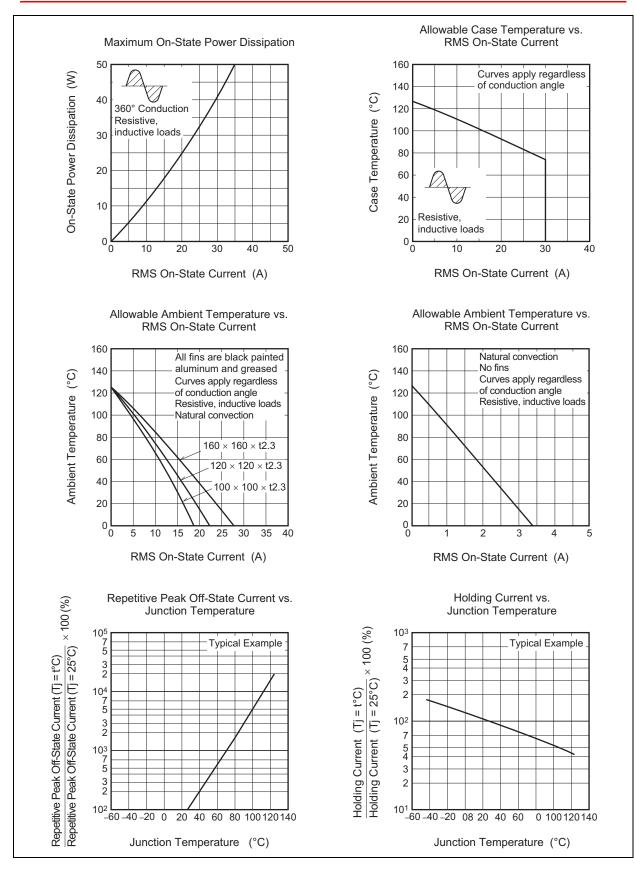
3. The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 0.3°C/W.

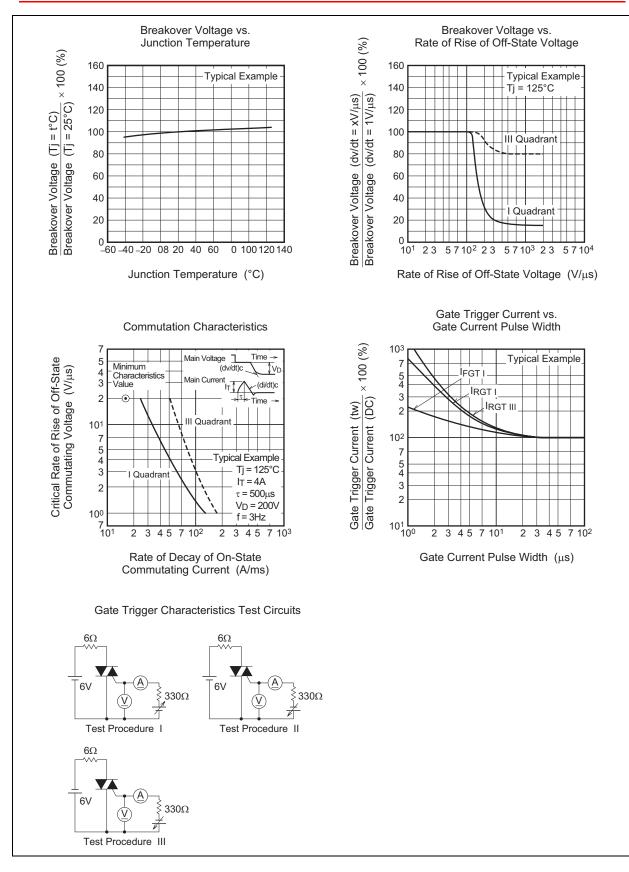
4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms inductive load		
1. Junction temperature Tj = 125°C	Supply Voltage → Time		
 Rate of decay of on-state commutating current (di/dt)c = -16 A/ms 	Main Current → Time		
3. Peak off-state voltage V _D = 400V	Main Voltage		

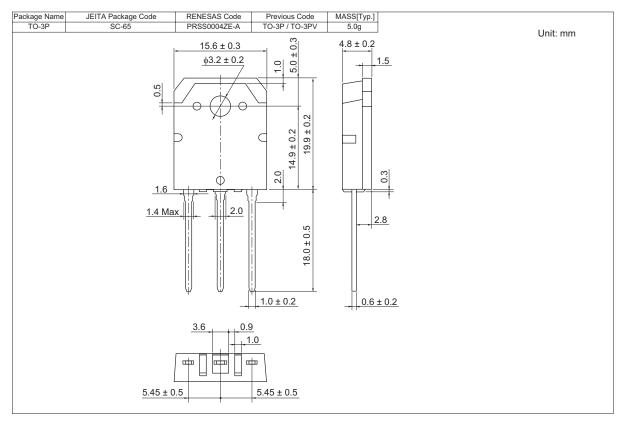
Performance Curves







Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	20	Type name	BCR30AM-12LA
Lead form	Plastic Magazine (Tube)	30	Type name – Lead forming code	BCR30AM-12LA-A8

Note : Please confirm the specification about the shipping in detail.

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

- <section-header>

 Image: States

 Present States

 States

 Present State



http://www.renesas.com

Refer to "http://www.renesas.com/en/network" for the latest and detailed information.

Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd. 7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd. 1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510